



0039-7271-2SRD

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2-25-02  
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IN THE UNITED STATES PATENT & TRADEMARK OFFICE

TC 2800 MAIL ROOM

IN RE APPLICATION OF:

DAISABURO TAKASHIMA ET AL.

: GROUP ART UNIT: 2826

SERIAL NO: 09/340,720 ✓

FILED: JUNE 29, 1999

: EXAMINER: DICKY, T.

FOR: SEMICONDUCTOR DEVICE

AMENDMENT

ASSISTANT COMMISSIONER FOR PATENTS  
WASHINGTON, D.C. 20231

SIR:

In response to the Official Action dated August 15, 2001, please amend the above-identified application as follows:

IN THE TITLE

Please amend the title on page 1, line 1, to read as follows:<sup>1</sup>

✓ MOSFET HAVING HIGH AND LOW DIELECTRIC MATERIALS

IN THE CLAIMS

Please amend the claims to read as shown in clean form below:<sup>2</sup>

1. (Amended) A semiconductor device comprising:

A1 Sub B

<sup>1</sup>The changes being made to the title are shown using underscoring and bracketing in the attachment hereto.

<sup>2</sup>The changes being made to the claims are shown using underscoring and bracketing in the attachment hereto.